Calculation part 5 A grating is fabricated by deep etching of grooves in silicon. The silicon wafer is 300 µm thick and the etched groves are 50 µm deep. Two test samples are fabricated; in the first the grooves are filed with Gold (Au), in the other the grooves are filled with Indium (In). Sketch of grooves viewed from the side. To investigate the filling quality, X-ray microscopy images are taken of the two gratings using 20 keV monochrome radiation. The result are two "Zebra-like" images showing brighter and darker stripes. Calculate the relative intensities for the darker and the brighter stripes in the two images. (Images are often normalized to the intensity value "one" when no object is applied.) Exam 2012-11-01 ex 5 as; = 10,397 cm-1 QAU = 1523,0 cm dly = 149,4 cm-1 Do = 1 4 5-X = 10,397.0,03 = 0,31190  $\Phi_{ij} = e^{-\alpha x} = e^{-0.31190} = 0.732$ QAU·XA = 1523,0.0,005 - 7,615 Remaining Si ds: Xis: = 10,397.0,025 = 0,2599 Ф = e-dau. XAM. e-asi. Xrsi = e (7,615 +0,2599) = 0,000380 QIn. X/n = 149,4.0,005 = 0,747 Remaining Si, same 45 for Au 0,2599  $0 = e^{-(\alpha x)_{1n} + (\alpha x)_{5i}} - e^{-(0.747 + 0.2599)} = 0,365$ First image pattern Only silicon: 0,732 intrusity (white) Av (sold) : 0,000 4 intensity (black) 2: nd sinage pattern Only silicon: 0,732 intensity (while) In (indium) ; 0,362 intensity (gray)